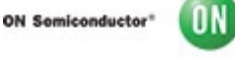

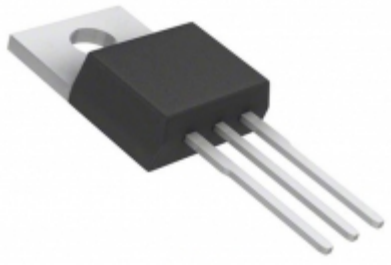










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|   | <h2 style="color: red;">FQP4N90C</h2> |
| | <p>Hersteller-Teilenummer: FQP4N90C</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 900V 4A TO-220</p> <p>Datenblätter: 1.FQP4N90C.pdf 2.FQP4N90C.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 19980 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|--|
| Teilenummer | FQP4N90C |
| Hersteller | Fairchild/ON Semiconductor |
| Beschreibung | MOSFET N-CH 900V 4A TO-220 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 19980 pcs Stock |
| Serie | QFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Verlustleistung (max) | 140W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 900V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 4A (Tc) |
| Rds On (Max) @ Id, Vgs | 4.2 Ohm @ 2A, 10V |
| VGS (th) (Max) @ Id | 5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 22nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 960pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±30V |
| Verpackung | Tube |

FQP4N90C ist neu im Original, Suche FQP4N90C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP4N90C Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP4N90C: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|---|
|  <p>FQP4P25 Fairchild/ON Semiconductor MOSFET P-CH 250V 4A TO-220</p> |  <p>FQP4N80 Fairchild/ON Semiconductor MOSFET N-CH 800V 3.9A TO-220</p> |  <p>FQP4P40 AMI Semiconductor / ON Semiconductor MOSFET P-CH 400V 3.5A TO-220</p> |  <p>FQP50N03 F FQP50N03 F</p> |
|  <p>FQP4P25 AMI Semiconductor / ON Semiconductor MOSFET P-CH 250V 4A TO-220</p> |  <p>FQP4N90 AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 4.2A TO-220</p> |  <p>FQP4N80 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 3.9A TO-220</p> |  <p>FQP4N90 Fairchild/ON Semiconductor MOSFET N-CH 900V 4.2A TO-220</p> |

heiße Teile

Mehr

| | | | | |
|--------------|--------------------|--------------------|--------------------|--------------------|
| ⊗ FQP44N10 | ↔ FQP44N10 | ⇒ FQP44N10F | D FQP44N10F | ⇒ FQP45N03L |
| ⊣ FQP45N03LM | ⊗ FQP45N15V2 | D FQP45N15V2 | ⇒ FQP45N20A | ⇒ FQP46N15 |
| ⊗ FQP46N15 | ⊣ FQP47N06 | ⊗ FQP47P06 | ↔ FQP47P06 | ⇒ FQP47P06L |
| D FQP47P06_ | ⊗ FQP47P06_NW82049 | ⊣ FQP47P06_NW82049 | ⊗ FQP47P06_SW82049 | ⇒ FQP47P06_SW82049 |
| ⇒ FQP4N20L | ↔ FQP4N20L | ⊗ FQP4N60C | ⊣ FQP4N65C | ⇒ FQP4N90C |
| ↔ FQP50N03 | ⇒ FQP50N03C | D FQP50N06 | ⊗ FQP50N06 | ⊣ FQP50N06L |
| ⊗ FQP50N06L | D FQP50N08 | ⇒ FQP55N06 | ↔ FQP55N06 | ⇒ FQP55N10 |
| ⊣ FQP55N10 | ⊗ FQP58N08 | ↔ FQP58N08 | ⇒ FQP5N20L | ⇒ FQP5N20L |
| ⊗ FQP5N50C | ⊣ FQP5N50C | ⊗ FQP5N60C | D FQP5N60C | ⇒ FQP630TSTU |
| ↔ FQP630TSTU | ⊗ FQP65N06 | ⊣ FQP65N06 | ⊗ FQP6N40C | ⇒ FQP6N40C |

Contact us: Info@Y-IC.com

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